REMARKS

The Office Action states that claims 12-15 (Group I) are drawn to a metal-oxide semiconductor field-effect transistor (MOSFET) classified in class 257, subclass 347 and that claims 1-11 and 16-20 (Group II) are drawn to a method for forming a MOSFET classified in class 438, subclass 149. The Office Action requires election of either Group I or Group II for examination. Applicants elect Group II (claims 1-11 and 16-20) without traverse.

To the extent necessary, a petition for an extension of time under 37 C.F.R. § 1.136 is hereby made. Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account 50-1070 and please credit any excess fees to such deposit account.

Respectfully submitted,

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Date: April 25, 2005

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